

LED NUMERIC DISPLAY, BIG SEGMENT DISPLAY
BL-SE1200X-11
Features:

- Ø 312.0mm (12.0") numeric segment series, BIG SEGMENT DISPLAY
- Ø Low current operation.
- Ø Excellent character appearance.
- Ø Easy mounting on P.C. Boards or sockets.
- Ø I.C. Compatible.
- Ø ROHS Compliance.


RoHS Compliance
Super Bright
Electrical-optical characteristics: (Ta=25°C) (Test Condition: IF=20mA)

Part No		Chip			VF Unit:V		Iv
Common Cathode	Common Anode	Emitte d Color	Material	λ_P (nm)	Typ	Max	TYP.(mcd)
BL-SE1200A-11S-XX	BL-SE1200B-11S-XX	Hi Red	GaAlAs/GaAs,SH	660	1.85	2.20	200
BL-SE1200A-11D-XX	BL-SE1200B-11D-XX	Super Red	GaAlAs/GaAs,DH	660	1.85	2.20	225
BL-SE1200A-11UR-X X	BL-SE1200B-11UR-X X	Ultra Red	GaAlAs/GaAs,DDH	660	1.85	2.20	250
BL-SE1200A-11E-XX	BL-SE1200B-11E-XX	Orange	GaAsP/GaP	635	2.10	2.50	200
BL-SE1200A-11Y-XX	BL-SE1200B-11Y-XX	Yellow	GaAsP/GaP	585	2.10	2.50	170
BL-SE1200A-11G-XX	BL-SE1200B-11G-XX	Green	GaP/GaP	570	2.20	2.50	210

Ultra Bright
Electrical-optical characteristics: (Ta=25°C) (Test Condition: IF=20mA)

Part No		Chip			VF Unit:V		Iv
Common Cathode	Common Anode	Emitted Color	Material	λ_P (nm)	Typ	Max	TYP.(mcd)
BL-SE1200A-11UHR-XX	BL-SE1200B-11UHR-X X	Ultra Red	AlGaInP	645	2.10	2.50	250
BL-SE1200A-11UE-XX	BL-SE1200B-11UE-XX	Ultra Orange	AlGaInP	630	2.10	2.50	210
BL-SE1200A-11YO-XX	BL-SE1200B-11YO-XX	Ultra Amber	AlGaInP	619	2.10	2.50	210
BL-SE1200A-11UY-XX	BL-SE1200B-11UY-XX	Ultra Yellow	AlGaInP	590	2.10	2.50	210
BL-SE1200A-11UG-XX	BL-SE1200B-11UG-XX	Ultra Green	AlGaInP	574	2.20	2.50	225
BL-SE1200A-11PG-XX	BL-SE1200B-11PG-XX	Ultra Pure Green	InGaN	525	3.80	4.50	250
BL-SE1200A-11B-XX	BL-SE1200B-11B-XX	Ultra Blue	InGaN	470	2.70	4.20	230
BL-SE1200A-11W-XX	BL-SE1200B-11W-XX	Ultra White	InGaN	/	2.70	4.20	230

-XX: Surface / Lens color :

Number	0	1	2	3	4	5
Ref Surface Color	White	Black	Gray	Red	Green	
Epoxy Color	Water clear	White diffused	Red Diffused	Green Diffused	Yellow Diffused	

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Absolute maximum ratings (Ta=25°C)

Parameter	S	D	UR	E	Y	G	Unit
Forward Current I_F	25	25	25	25	25	30	mA
Power Dissipation P_d	60	60	60	60	60	65	mW
Reverse Voltage V_R	5	5	5	5	5	5	V
Peak Forward Current I_{PF} (Duty 1/10 @1KHZ)	150	150	150	150	150	150	mA
Operation Temperature T_{OPR}	-40 to +80						°C
Storage Temperature T_{STG}	-40 to +85						°C
Lead Soldering Temperature T_{SOL}	Max.260±5°C for 3 sec Max. (1.6mm from the base of the epoxy bulb)						°C

Absolute maximum ratings (Ta=25°C)

Parameter	UHR	UE	YO	UY	UG	PG	UB	UW	Unit
Forward Current I_F	30	30	30	30	30	30	30	30	mA
Power Dissipation P_d	75	65	65	65	75	110	120	120	mW
Reverse Voltage V_R	5	5	5	5	5	5	5	5	V
Peak Forward Current I_{PF} (Duty 1/10 @1KHZ)	150	150	150	150	150	150	100	100	mA
Operation Temperature T_{OPR}	-40 to +80								°C
Storage Temperature T_{STG}	-40 to +85								°C
Lead Soldering Temperature T_{SOL}	Max.260±5°C for 3 sec Max. (1.6mm from the base of the epoxy bulb)								°C

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Typical electrical-optical characteristics curves:



- (1) - GaAsP/GaAs 655nm/Red
- (2) - GaP 570nm/Yellow Green
- (3) - GaAsP/GaP 585nm/Yellow
- (4) - GaAsP/GaP 635nm/Orange & Hi-Eff Red
- (5) - GaP 700nm/Bright Red
- (6) - GaAlAs/GaAs 660nm/Super Red
- (8) - GaAsP/GaP 610nm/Super Red
- (9) - GaAlAs 880nm
- (10) - GaAs/GaAs & GaAlAs/GaAs 940nm
- (A) - GaN/SiC 430nm/Blue
- (B) - InGaN/SiC 470nm/Blue
- (C) - InGaN/SiC 505nm/Ultra Green
- (D) - InGaAlSiC 525nm/Ultra Green



FORWARD VOLTAGE (Vf)
FORWARD CURRENT VS.
FORWARD VOLTAGE



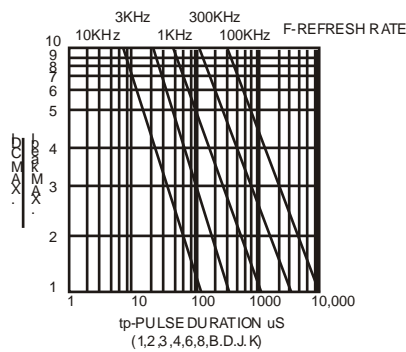
FORWARD CURRENT (mA)
RELATIVE LUMINOUS
INTENSITY VS. FORWARD
CURRENT



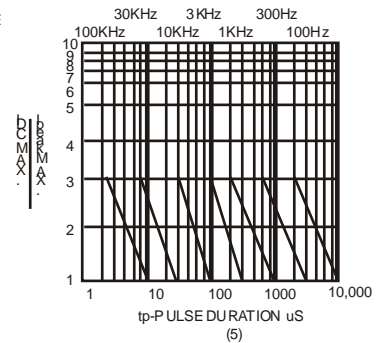
AMBIENT TEMPERATURE Ta()
FORWARD CURRENT VS. AMBIENT
TEMPERATURE



AMBIENT TEMPERATURE Ta()



tp-PULSE DURATION uS
(1,2,3,4,6,8,B,D,J,K)



tp-PULSE DURATION uS
(5)

NOTE:25 free air temperature unless otherwise specified